

# The Oscillator Specification Sheet

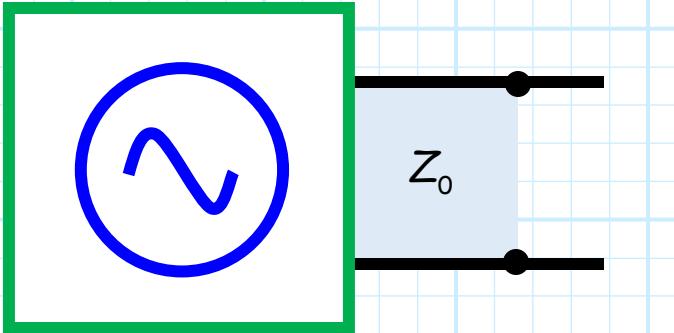


Figure 1: The HMC-C200 Dielectric Resonator Oscillator (DRO) module covers 8.0 to 8.3 GHz.

## Carrier Frequency

Microwave oscillators are generally specified in MHz or GHz.

Electronic oscillators have been made that work well into the millimeter wave region (e.g., 100 GHz), but we typically find that increasing the oscillating frequency means **decreased** oscillator performance (e.g., lower power, less stability) and increased oscillator cost!

Some oscillators are **tunable** (e.g. Voltage Controlled Oscillators), so the carrier frequency in this case is specified as a **bandwidth** (e.g., 2.3-3.9 GHz).

## Carrier Power

This is the **available power** of the source.

This value is generally specified in **dBm** for **low-power** oscillators, **Watts** for **high-power** oscillators.

Typical values for "small-signal" oscillators are **5 to 20 dBm** (hey, the same values as for **mixer LO** drive power—what a coincidence!).

## Accuracy

Specified in  $\pm$  **ppm** over the temperature range of the device (e.g.,  $-25^\circ\text{ C}$  to  $85^\circ\text{ C}$ ).

→ This value is usually considered the **stability** of the oscillator!

## Harmonics and Spurs

Typically specified as the power of the **largest** spurious and/or harmonic signal, typically in terms **dBc**. For example:

*All spurious signal are less than -50 dBc*

This value depends on the quality **Q** of the resonator, as well as the amount of **filtering** provided between the oscillator and its output port.

## Phase Noise

Specified in **dBc** in a **one Hz bandwidth** at one or **more** specific frequencies from the carrier.

e.g., -80 dBc in a 1Hz bandwidth at 1 kHz from the carrier frequency  $f_0$

Every single word in this specification is required in order to unambiguously specify phase noise!!!

The amount of phase noise exhibited by an oscillator depends on the **Q of the resonator**, the **carrier frequency** (higher frequencies generally exhibit worse phase noise), and the amount of **noise coupled** into the device through the power supply or tuning port.

## Noise Floor

This is the thermal noise (as opposed to phase noise) at the output of the oscillator. It is specified in terms of its **spectral power density**, assumed to be a **constant** value in mW/Hz, and generally specified as "dBm, in a 1 Hz bandwidth", or as "dBm/Hz".

## DC power

Oscillators generally will **require** some specific **DC voltage**, and thus "pull" some amount of **DC current**.

The product of the two (DC volts and DC current) is of course the **DC power**  $P_{DC}$  requirement of the oscillator.

## Efficiency

This coefficient expresses the **efficiency** at which the oscillator converts its DC power into microwave signal power (i.e., carrier power).

Efficiency  $\eta$  is simply the ratio of the **available power** (in mW) of the oscillator (i.e., **carrier power**  $P_C$ ) to the power (in mW) provided to the oscillator from the **DC power supply** (i.e.,  $P_{DC} = V_{DC} I_{DC}$ ):

$$\eta = \frac{P_C}{P_{DC}}$$

This coefficient varies from a **minimum of 0** (bad!) to a **maximum of 1.0** (good!).

## Frequency Pulling

Usually specified as the **maximum frequency shift** (in hertz or in ppm) from nominal frequency  $\omega_0$ , due to some worst-case load (expressed in VSWR, return loss, etc.). For example:

*Pulling is less than 0.1 MHz when driving a 2.5:1 VSWR load.*

This value again depends on the **Q of the resonator** and the **carrier frequency** (higher frequencies generally exhibit worse

pulling). It likewise depends on the amount of **isolation** provided between the oscillator and its output port.

### Frequency Pushing

Expressed in units of Hz/V or Hz/mV, or sometimes as ppm/V or ppm/mV. Can be either a positive or a negative number.

This value depends on the **Q of the resonator**, the **carrier frequency** (higher frequencies generally exhibit worse pushing), and the amount of **internal voltage regulation** built into the oscillator.